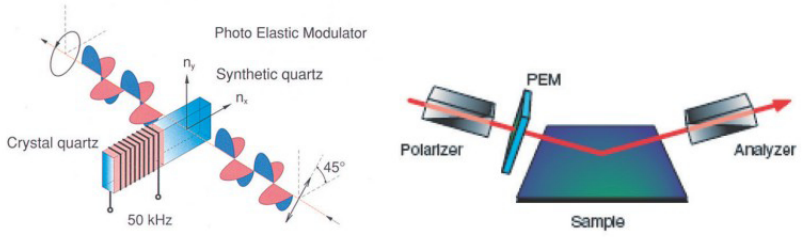


橢圓儀 Ellipsometer

M-220 / M-550 Ellipsometer

Ellipsometry is a method for determining the refractive index and extinction coefficients of a sample by measuring the change in polarization state of surface reflected light. Film thickness and optical constants of an adsorption layer or oxide film on a substrate surface can be determined with exceptional sensitivity. Conventional interference spectroscopy utilizes light passed through separate optical paths, while ellipsometry is a form of interferometry that uses two vibrational components with the same optical path, providing measurements with excellent accuracy and repeatability.



Multilayer film analysis

JASCO developed a special program for calculating the film thickness and optical constants for each layer of a multilayer film based on the ellipsometric parameters (Δ, Ψ) λ = for the material. A multilayer film model is developed for the sample, the film thickness and optical constants optimized to minimize the deviation from the measured values.

Mapping analysis

The figure shows the thickness distribution of silicon nitride on a four-inch substrate. An average film thickness of 902 Å and a refractive index of 2.01 were obtained. The film is clearly thicker towards the center and thinner toward the periphery.

